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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**
(Use several sheets, if necessary)

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APPLICANT
Atsushi YAMAGUCHI et al.

FILING DATE
March 26, 2001

GROUP
2826

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	PATENT NUMBER	ISSUE DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA					
	AB					
	AC					

FOREIGN PATENT OR PUBLISHED FOREIGN PATENT APPLICATION

	DOCUMENT NO.	PUBL. DATE	COUNTRY OR PATENT OFFICE	CLASS	SUB CLASS	TRANSLATION YES NO
R. N.	AH A 2000-77785	03/00	JP			
A. S.	AI A 2000-58915	02/00	JP			
A. S.	AJ A 2000-21789	01/00	JP			
A. S.	AK A 2000-4063	01/00	JP			
	AL					
	AM					
	AN					

OTHER DOCUMENTS (Including Author, Title, Date, Relevant Pages, Place of Publication)

R. N.	AM	Shuji Nakamura et al., "InGaN/GaN/AlGaIn-Based Laser-Diodes with Modulation-Doped Strained-Layer Superlattices," <u>Jpn. J. Appl. Phys.</u> , V. 36, 1997, pp. 1568-1571.
A. S.	AN	<u>Applied Physics</u> , V. 68, No. 7, 1999, pp. 793-796.
	AO	

EXAMINER

DATE CONSIDERED

EXAMINER: Initial citation considered. Draw line through citation if not in conformance and not considered.
Include copy of this form with next communication to applicant.